

# SN55182, SN75182 DUAL DIFFERENTIAL LINE RECEIVERS

SLLS092D – OCTOBER 1972 – REVISED APRIL 1998

- Single 5-V Supply
- Differential Line Operation
- Dual Channels
- TTL Compatibility
- $\pm 15$ -V Common-Mode Input Voltage Range
- $\pm 15$ -V Differential Input Voltage Range
- Individual Channel Strobes
- Built-In Optional Line-Termination Resistor
- Individual Frequency Response Controls
- Designed for Use With Dual Differential Drivers SN55183 and SN75183
- Designed to Be Interchangeable With National Semiconductor DS7820A and DS8820A

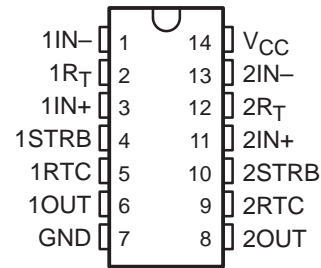
## description

The SN55182 and SN75182 dual differential line receivers are designed to sense small differential signals in the presence of large common-mode noise. These devices give TTL-compatible output signals as a function of the polarity of the differential input voltage. The frequency response of each channel can be easily controlled by a single external capacitor to provide immunity to differential noise spikes. The output goes to a high level when the inputs are open circuited. A strobe input (STRB) is provided that, when in the low level, disables the receiver and forces the output to a high level.

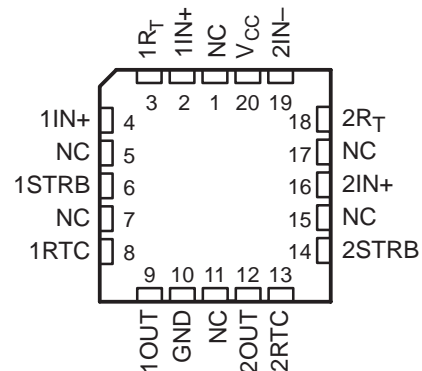
The receiver is of monolithic single-chip construction, and both halves of the dual circuits use common power-supply and ground terminals.

The SN55182 is characterized for operation over the full military temperature range of  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ . The SN75182 is characterized for operation from  $0^{\circ}\text{C}$  to  $70^{\circ}\text{C}$ .

SN55182 . . . J OR W PACKAGE  
SN75182 . . . N PACKAGE  
(TOP VIEW)



SN55182 . . . FK PACKAGE  
(TOP VIEW)



NC – No internal connection

**THE SN55182 IS NOT RECOMMENDED  
FOR NEW DESIGNS**

FUNCTION TABLE

| INPUTS |                 | OUTPUT<br>OUT |
|--------|-----------------|---------------|
| STRB   | V <sub>ID</sub> |               |
| L      | X               | H             |
| H      | H               | H             |
| H      | L               | L             |

H =  $V_I \geq V_{IH}$  min or  $V_{ID}$  more positive than  $V_{TH}$  max  
L =  $V_I \leq V_{IL}$  max or  $V_{ID}$  more negative than  $V_{TL}$  max  
X = irrelevant



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**TEXAS  
INSTRUMENTS**

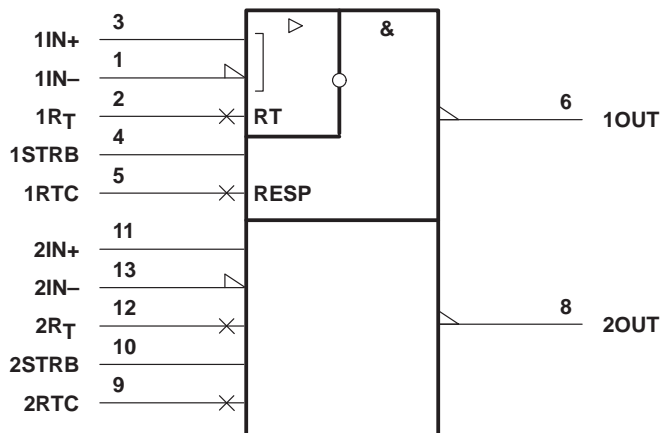
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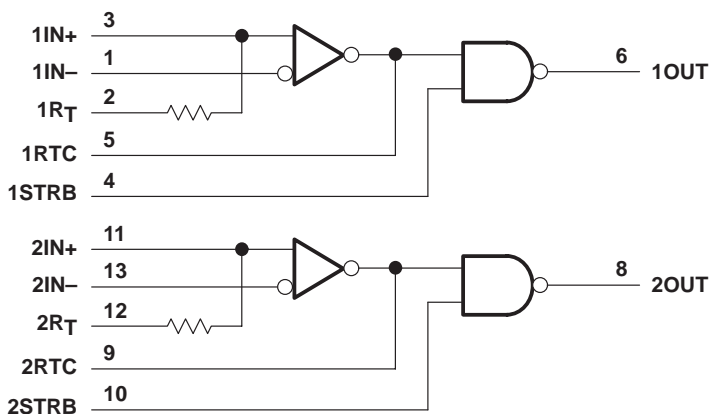
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## logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the J, N, and W packages.

## logic diagram (positive logic)

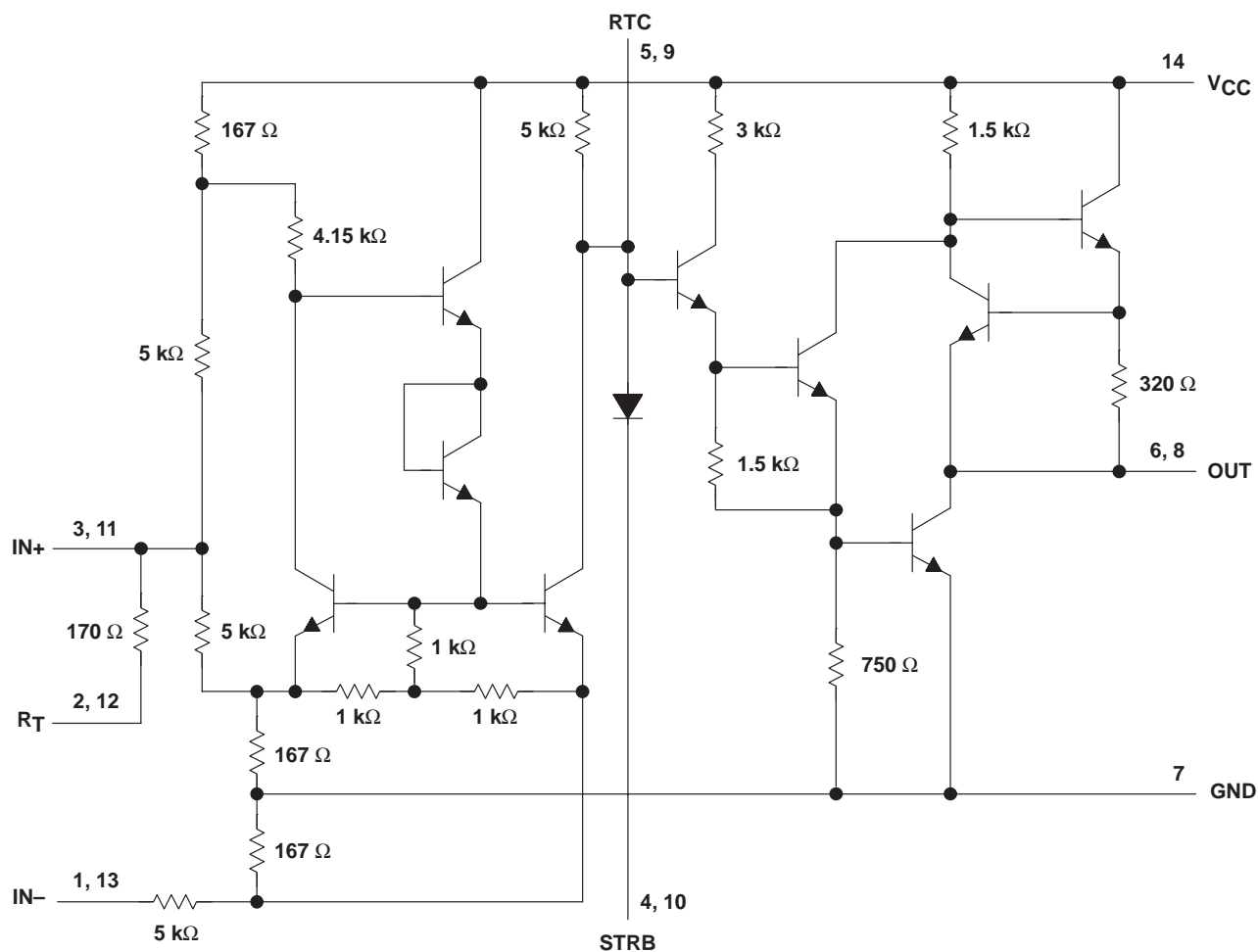


Pin numbers shown are for the J, N, and W packages.

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## schematic (each receiver)



Resistor values shown are nominal.  
Pin numbers shown are for the J, N, and W packages.

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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

|  |  |
|--|--|
| Supply voltage, $V_{CC}$ (see Note 1)  | 8 V  |
| Common-mode input voltage, $V_{IC}$  | $\pm 20$ V                                     |
| Differential input voltage, $V_{ID}$ (see Note 2)                            | $\pm 20$ V                                     |
| Strobe input voltage, $V_{I(STRB)}$  | 8 V  |
| Output sink current  | 50 mA  |
| Continuous total power dissipation   | See Dissipation Rating Table                   |
| Storage temperature range, $T_{stg}$   | $-65^{\circ}\text{C}$ to $150^{\circ}\text{C}$ |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: N package      | $260^{\circ}\text{C}$                          |
| Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J or W package | $300^{\circ}\text{C}$                          |
| Case temperature for 60 seconds, $T_C$ : FK package                          | $260^{\circ}\text{C}$                          |

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to network ground terminal.  
2. Differential voltage values are at the noninverting terminal with respect to the inverting terminal.

DISSIPATION RATING TABLE

| PACKAGE | $T_A \leq 25^{\circ}\text{C}$ | DERATING FACTOR                  | $T_A = 70^{\circ}\text{C}$ | $T_A = 125^{\circ}\text{C}$ |
|---------|-------------------------------|----------------------------------|----------------------------|-----------------------------|
|         | POWER RATING                  | ABOVE $T_A = 25^{\circ}\text{C}$ | POWER RATING               | POWER RATING                |
| FK‡     | 1375 mW                       | 11.0 mW/ $^{\circ}\text{C}$      | 880 mW                     | 275 mW                      |
| J‡      | 1375 mW                       | 11.0 mW/ $^{\circ}\text{C}$      | 880 mW                     | 275 mW                      |
| N       | 1150 mW                       | 9.2 mW/ $^{\circ}\text{C}$       | 736 mW                     | –                           |
| W‡      | 1000 mW                       | 8.0 mW/ $^{\circ}\text{C}$       | 640 mW                     | 200 mW                      |

‡ In the FK, J, and W packages, SN55182 chips are alloy mounted.

## recommended operating conditions

|   | SN55182 |     |          | SN75182 |     |          | UNIT               |
|---|---------|-----|----------|---------|-----|----------|--------------------|
|   | MIN     | NOM | MAX      | MIN     | NOM | MAX      |                    |
| Supply voltage, $V_{CC}$                        | 4.5     | 5   | 5.5      | 4.5     | 5   | 5.5      | V                  |
| Common-mode input voltage, $V_{IC}$             |         |     | $\pm 15$ |         |     | $\pm 15$ | V                  |
| High-level strobe input voltage, $V_{IH(STRB)}$ | 2.1     |     | 5.5      | 2.1     |     | 5.5      | V                  |
| Low-level strobe input voltage, $V_{IL(STRB)}$  | 0       |     | 0.9      | 0       |     | 0.9      | V                  |
| High-level output current, $I_{OH}$             |         |     | –400     |         |     | –400     | $\mu\text{A}$      |
| Low-level output current, $I_{OL}$              |         |     | 16       |         |     | 16       | mA                 |
| Operating free-air temperature, $T_A$           | –55     |     | 125      | 0       |     | 70       | $^{\circ}\text{C}$ |



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**electrical characteristics over recommended ranges of  $V_{CC}$ ,  $V_{IC}$ , and operating free-air temperature (unless otherwise noted)**

| PARAMETER             |  | TEST CONDITIONS†   |   | MIN                     | TYP‡ | MAX           | UNIT       |    |
|-----------------------|--|--|---|-------------------------|------|---------------|------------|----|
| $V_{IT+}$             | Positive-going input threshold voltage | $V_O = 2.5\text{ V}$ ,<br>$I_{OH} = -400\ \mu\text{A}$                                 | $V_{IC} = -3\text{ V to }3\text{ V}$  |                         |      | 0.5           | V          |    |
|                       |  |  | $V_{IC} = -15\text{ V to }15\text{ V}$  |                         |      | 1             |            |    |
| $V_{IT-}$             | Negative-going input threshold voltage | $V_O = 0.4\text{ V}$ ,<br>$I_{OL} = 16\text{ mA}$                                      | $V_{IC} = -3\text{ V to }3\text{ V}$  |                         |      | -0.5          | V          |    |
|                       |  |  | $V_{IC} = -15\text{ V to }15\text{ V}$  |                         |      | -1            |            |    |
| $V_{OH}$              | High-level output voltage              | $V_{ID} = 1\text{ V}$ , $V(\text{STRB}) = 2.1\text{ V}$ , $I_{OH} = -400\ \mu\text{A}$ |   | 2.5                     | 4.2  | 5.5           | V          |    |
|                       |  |  | $V_{ID} = -1\text{ V}$ , $V(\text{STRB}) = 0.4\text{ V}$ , $I_{OH} = -400\ \mu\text{A}$ | 2.5                     | 4.2  | 5.5           |            |    |
| $V_{OL}$              | Low-level output voltage               | $V_{ID} = -1\text{ V}$ , $V(\text{STRB}) = 2.1\text{ V}$ , $I_{OL} = 16\text{ mA}$     |   | 0.25                    | 0.4  |               | V          |    |
| $I_I$                 | Input current                          |  | Inverting input   | $V_{IC} = 15\text{ V}$  |      | 3             | 4.2        | mA |
|                       |  |  |   | $V_{IC} = 0$            |      | 0             | -0.5       |    |
|                       |  |  |   | $V_{IC} = -15\text{ V}$ |      | -3            | -4.2       |    |
|                       |  |  | Noninverting input  | $V_{IC} = 15\text{ V}$  |      | 5             | 7          |    |
|                       |  |  |   | $V_{IC} = 0$            |      | -1            | -1.4       |    |
|                       |  |  |   | $V_{IC} = -15\text{ V}$ |      | -7            | -9.8       |    |
| $I_{IH}(\text{STRB})$ | High-level strobe input current        | $V(\text{STRB}) = 5.5\text{ V}$  |   |                         | 5    | $\mu\text{A}$ |            |    |
| $I_{IL}(\text{STRB})$ | Low-level strobe input current         | $V(\text{STRB}) = 0$   |   |                         | -1   | -1.4          | mA         |    |
| $r_i$                 | Input resistance                       |  | Inverting input   |                         | 3.6  | 5             | k $\Omega$ |    |
|                       |  |  | Noninverting input  |                         | 1.8  | 2.5           |            |    |
|                       | Line-terminating resistance            | $T_A = 25^\circ\text{C}$   |   | 120                     | 170  | 250           | $\Omega$   |    |
| $I_{OS}$              | Short-circuit output current           | $V_{CC} = 5.5\text{ V}$ ,<br>$V_O = 0$   |   | -2.8                    | -4.5 | -6.7          | mA         |    |
| $I_{CC}$              | Supply current (average per receiver)  |  | $V_{IC} = 15\text{ V}$ ,<br>$V_{ID} = -1\text{ V}$                                      |                         | 4.2  | 6             | mA         |    |
|                       |  |  | $V_{IC} = 0$ ,<br>$V_{ID} = -0.5\text{ V}$  |                         | 6.8  | 10.2          |            |    |
|                       |  |  | $V_{IC} = -15\text{ V}$ ,<br>$V_{ID} = -1\text{ V}$                                     |                         | 9.4  | 14            |            |    |

† Unless otherwise noted,  $V(\text{STRB}) \geq 2.1\text{ V}$  or open.

‡ All typical values are at  $V_{CC} = 5\text{ V}$ ,  $V_{IC} = 0$ , and  $T_A = 25^\circ\text{C}$ .

## switching characteristics, $V_{CC} = 5\text{ V}$ , $T_A = 25^\circ\text{C}$

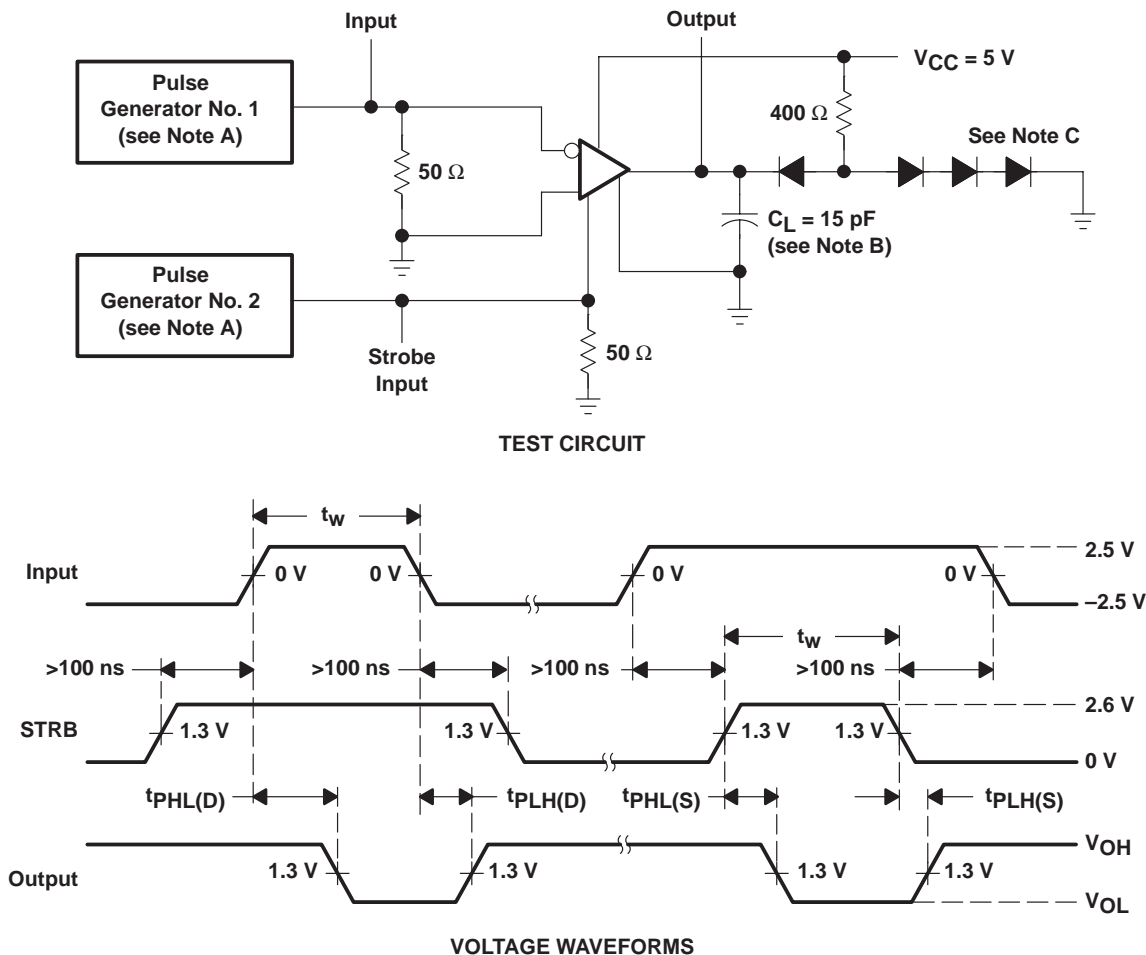
| PARAMETER           |   | TEST CONDITIONS       |                        |              | MIN | TYP | MAX | UNIT |
|---------------------|---|-----------------------|------------------------|--------------|-----|-----|-----|------|
| $t_{PLH}(\text{D})$ | Propagation delay time, low- to high-level output from differential input | $R_L = 400\ \Omega$ , | $C_L = 15\text{ pF}$ , | see Figure 1 |     | 18  | 40  | ns   |
| $t_{PHL}(\text{D})$ | Propagation delay time, high- to low-level output from differential input | $R_L = 400\ \Omega$ , | $C_L = 15\text{ pF}$ , | see Figure 1 |     | 31  | 45  | ns   |
| $t_{PLH}(\text{S})$ | Propagation delay time, low- to high-level output from STRB input         | $R_L = 400\ \Omega$ , | $C_L = 15\text{ pF}$ , | see Figure 1 |     | 9   | 30  | ns   |
| $t_{PHL}(\text{S})$ | Propagation delay time, high- to low-level output from STRB input         | $R_L = 400\ \Omega$ , | $C_L = 15\text{ pF}$ , | see Figure 1 |     | 15  | 25  | ns   |



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## PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The pulse generators have the following characteristics:  $Z_O = 50 \Omega$ ,  $t_r \leq 10 \text{ ns}$ ,  $t_f \leq 10 \text{ ns}$ ,  $t_w = 0.5 \pm 0.1 \mu\text{s}$ ,  $\text{PRR} \leq 1 \text{ MHz}$ .  
 B.  $C_L$  includes probe and jig capacitance.  
 C. All diodes are 1N3064 or equivalent.

Figure 1. Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS†

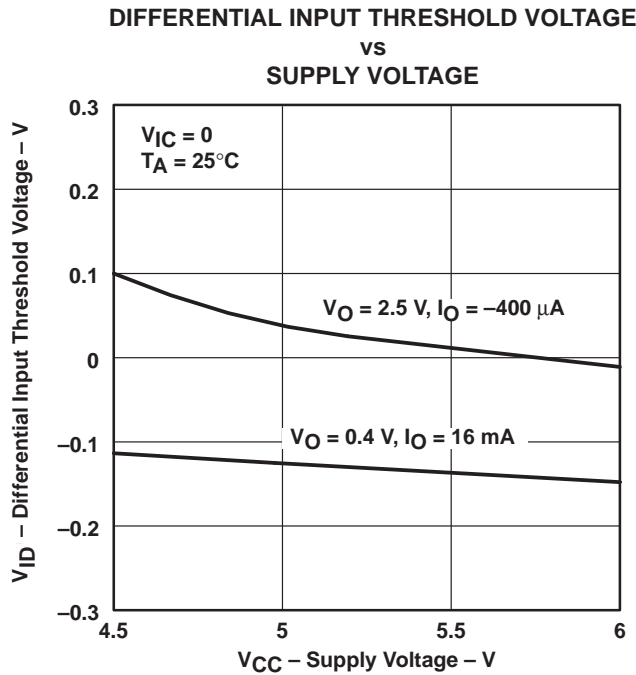


Figure 2

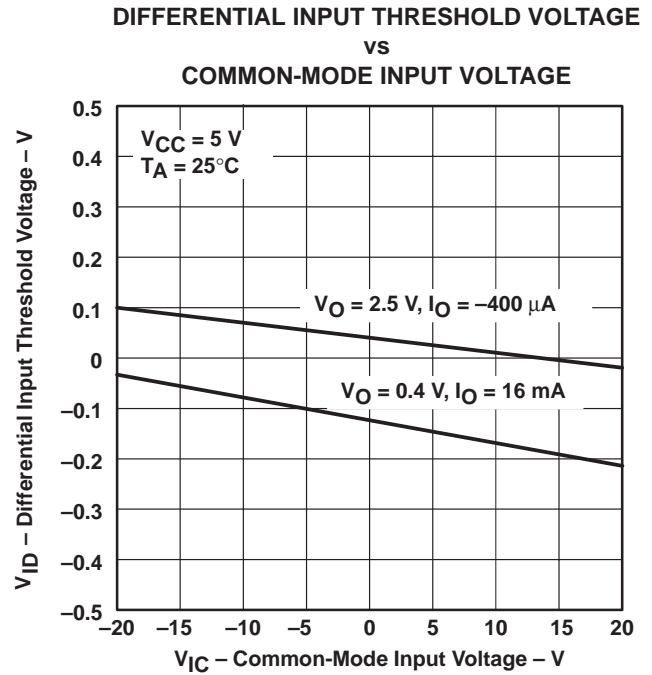


Figure 3

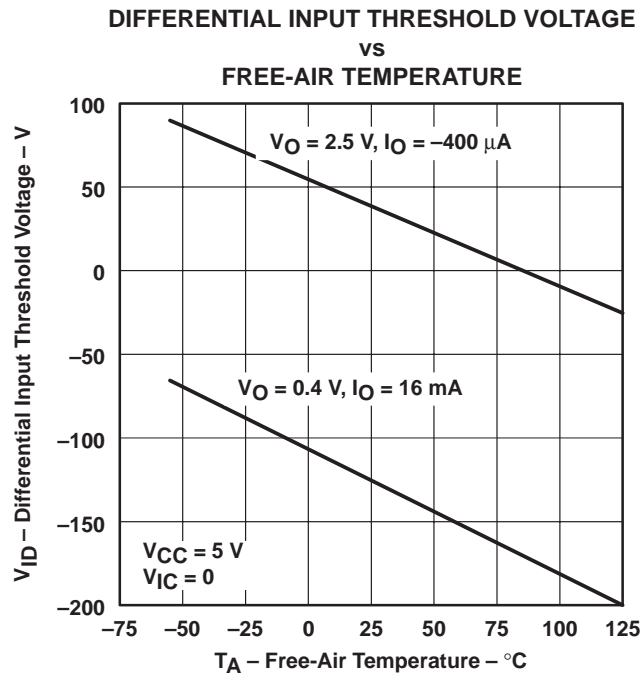


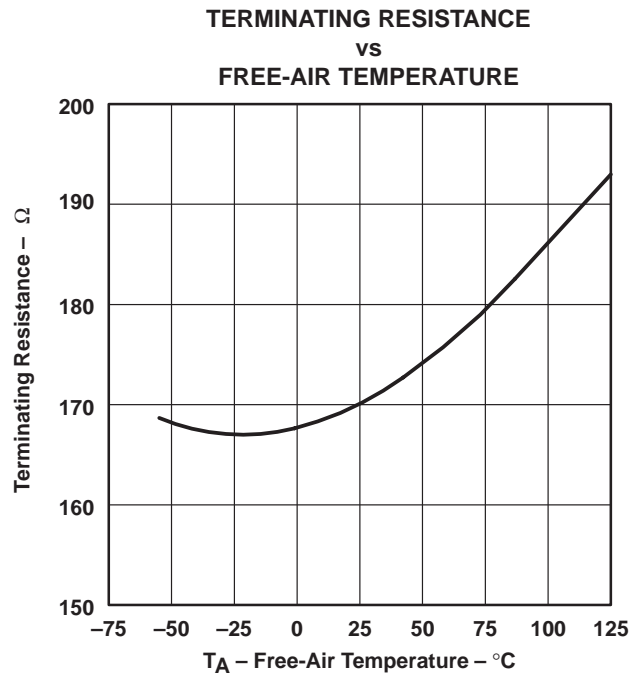
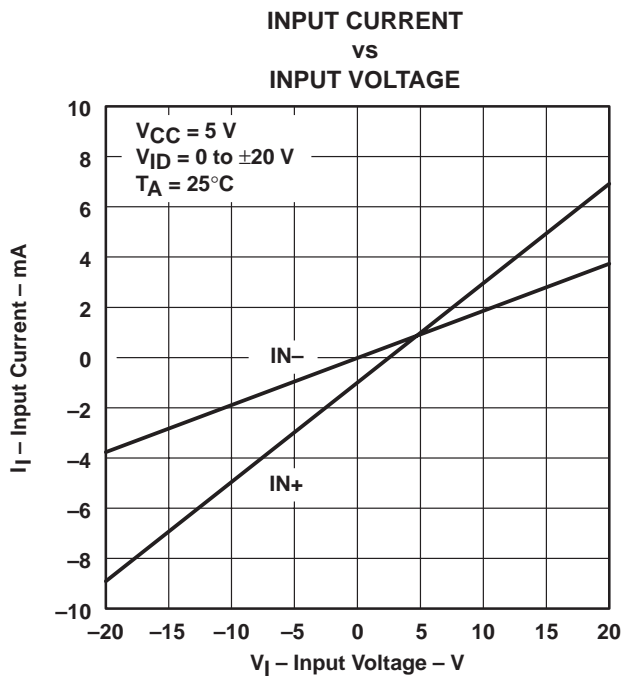
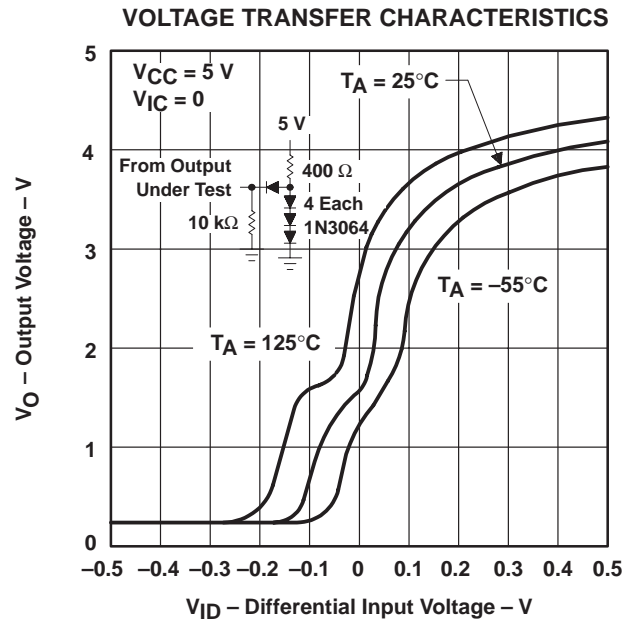
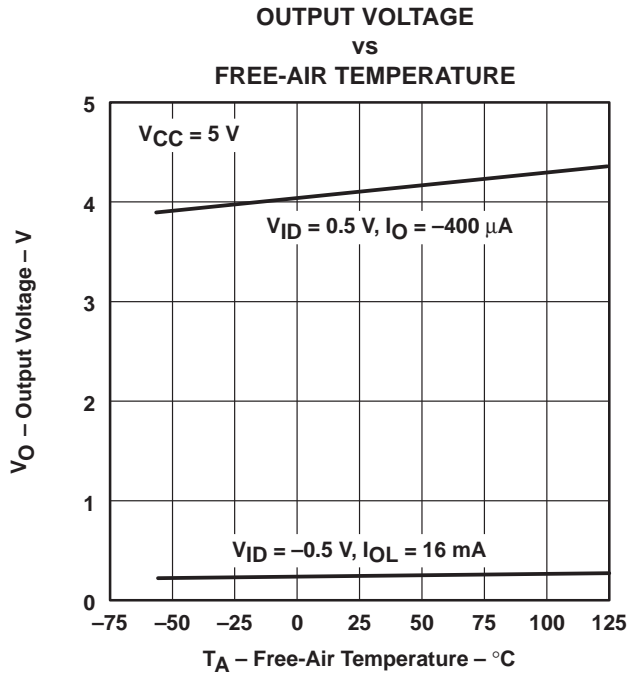
Figure 4

† Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.

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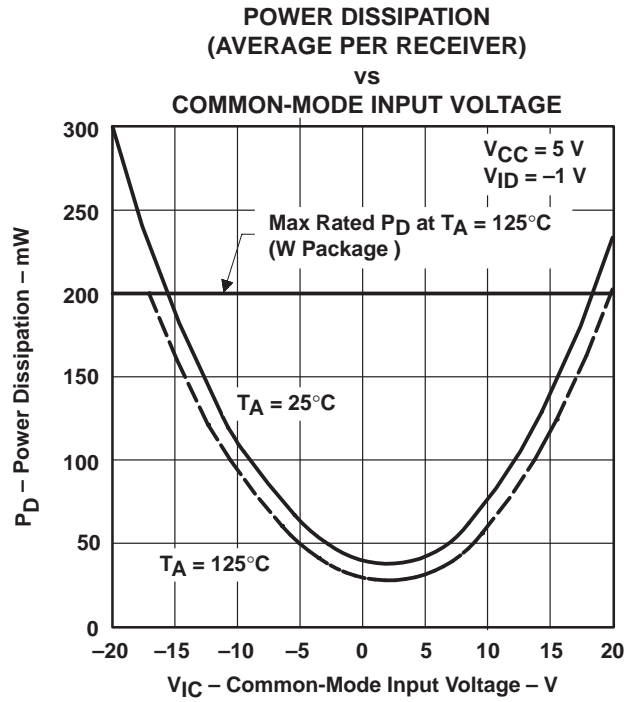
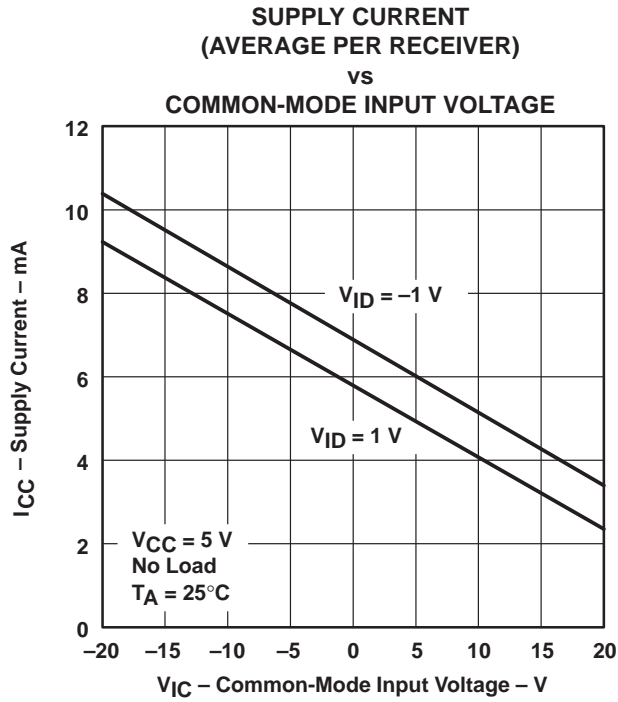
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TYPICAL CHARACTERISTICS†

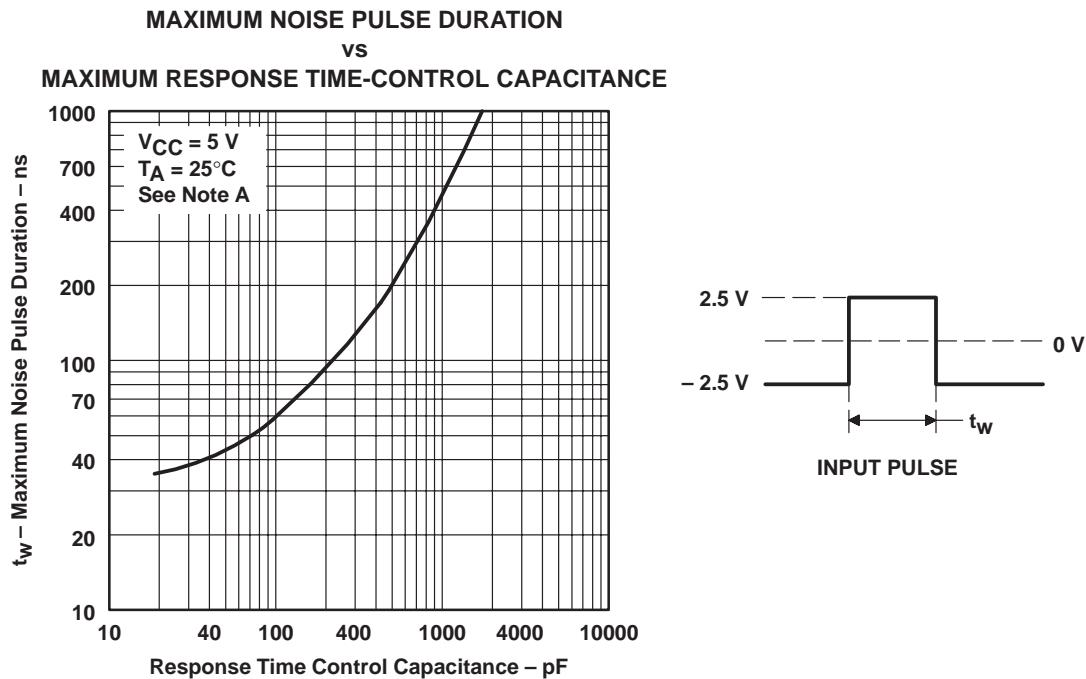


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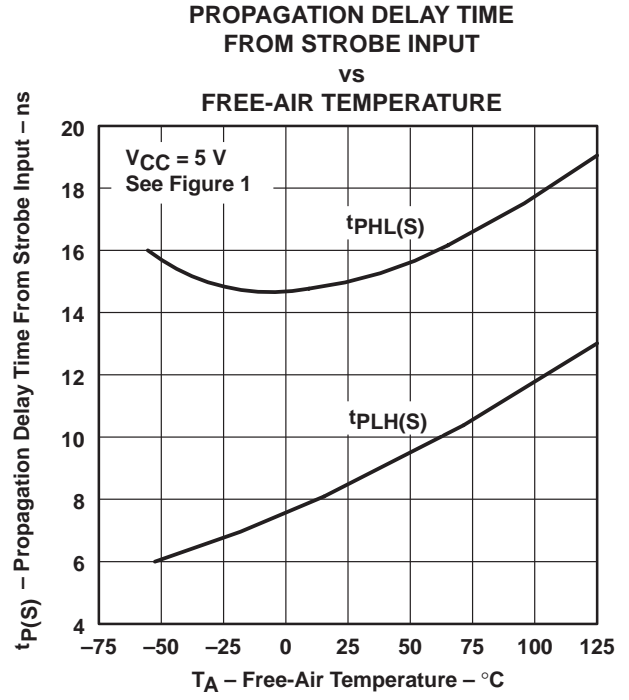
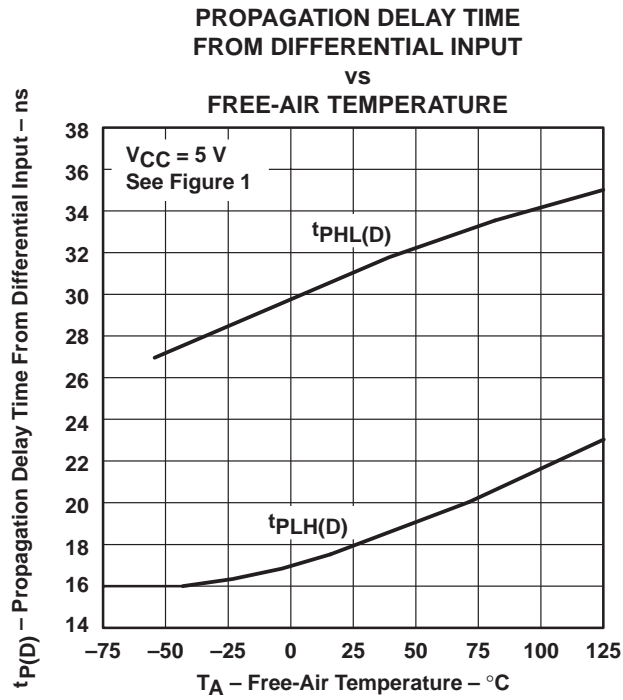


NOTE A: Figure 11 shows the maximum duration of the illustrated pulse that can be applied differently without the output changing from the low to high level.

**Figure 11**

† Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.

TYPICAL CHARACTERISTICS†

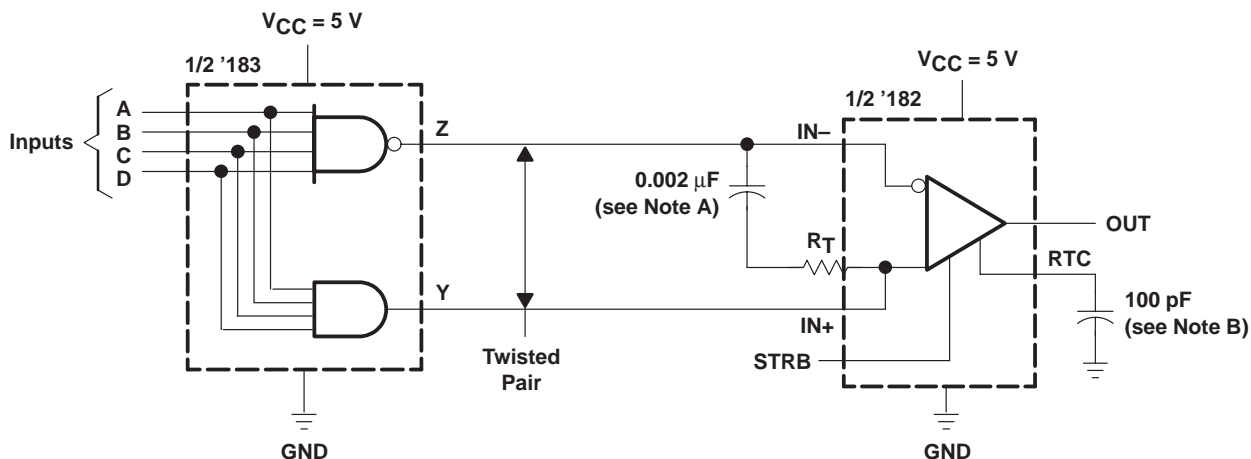


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## APPLICATION INFORMATION



NOTES: A. When the inputs are open circuited, the output is high. A capacitor may be used for dc isolation of the line-terminating resistor. At the frequency of operation, the impedance of the capacitor should be relatively small.

Example: let  $f = 5 \text{ MHz}$   
 $C = 0.002 \mu\text{F}$

$$Z_{(C)} = \frac{1}{2\pi f C} = \frac{1}{2\pi(5 \times 10^6)(0.002 \times 10^{-6})}$$

$$Z_{(C)} \approx 16\Omega$$

B. Use of a capacitor to control response time is optional.

**Figure 14. Transmission of Digital Data Over Twisted-Pair Line**

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